NSN 5961-01-194-7418

Semiconductor Device Set - Page 1 of 1



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Inclosure Material:
Glass all semiconductor device diode
Overall Length:
0.180 inches all semiconductor device diode
Terminal Length:
1.500 inches all semiconductor device diode
Overall Diameter:
0.075 inches all semiconductor device diode
Function For Which Designed:
Switching
Internal Configuration:
Junction contact all semiconductor device diode
Internal Junction Configuration:
Pn all semiconductor device diode
Component Function Relationship:
Matched
Component Name And Quantity:
3 semiconductor device diode
Mounting Method:
Terminal all semiconductor device diode
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon all semiconductor device diode
Voltage Rating In Volts Per Characteristic:
75.0 breakdown voltage, instantaneous all semiconductor device diode and 50.0 working peak reverse voltage all semiconductor device
diode
Current Rating Per Characteristic:
200.00 milliamperes forward current, average absolute all semiconductor device diode
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius ambient air all semiconductor device diode
Terminal Type And Quantity:
2 uninsulated wire lead all semiconductor device diode
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:

Fiig: A110a0

No